



BC846AW ~ BC850CW

NPN GENERAL PURPOSE TRANSISTORS

VOLTAGE 30/45/65 Volts **CURRENT** 150 mWatts

FEATURES

- General purpose amplifier applications
- NPN epitaxial silicon, planar design
- Collector current $I_C = 100\text{mA}$
- Lead free in comply with EU RoHS 2002/95/EC directives.
- Green molding compound as per IEC61249 Std. . (Halogen Free)

MECHANICAL DATA

- Case: SOT-323, Plastic
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0001 ounces, 0.005 grams

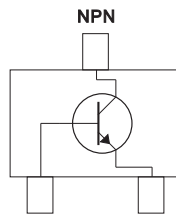
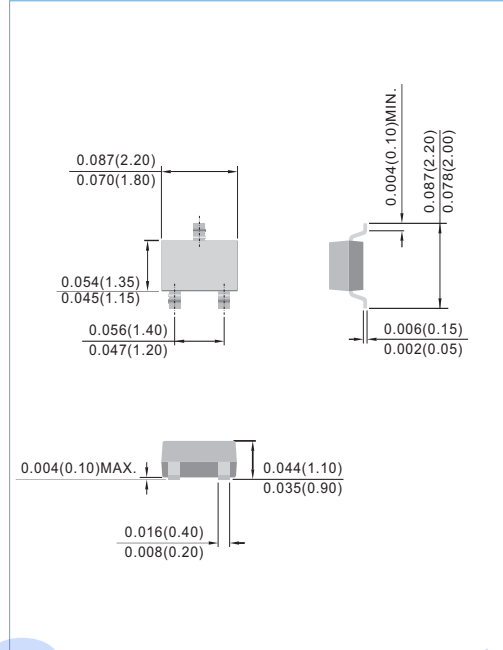


Fig.34

Device Marking:				
BC846AW=46A	BC847AW=47A	BC848AW=48A		
BC846BW=46B	BC847BW=47B	BC848BW=48B	BC849BW=49B	BC850BW=50B
	BC847CW=47C	BC848CW=48C	BC849CW=49C	BC850CW=50C

SOT-323

Unit : inch(mm)



ABSOLUTE RATINGS

PARAMETER	Symbol	Value	Units
Collector - Emitter Voltage	V_{CEO}	BC846W	65
		BC847W, BC850W	45
		BC848W, BC849W	30
Collector - Base Voltage	V_{CBO}	BC846W	80
		BC847W, BC850W	50
		BC848W, BC849W	30
Emitter - Base Voltage	V_{EBO}	BC846W	6.0
		BC847W, BC850W	6.0
		BC848W, BC849W	5.0
Collector Current - Continuous	I_C	100	mA

THERMAL CHARACTERISTICS

PARAMETER	Symbol	Value	Units
Max Power Dissipation (Note 1)	P_{TOT}	150	mW
Thermal Resistance	$R_{\theta JA}$	400	$^{\circ}\text{C}/\text{W}$
	$R_{\theta JC}$	100	$^{\circ}\text{C}/\text{W}$
Junction Temperature	T_J	-55 to 150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55 to 150	$^{\circ}\text{C}$

Note 1: Transistor mounted on FR-5 board 1.0 x 0.75 x 0.062 in.



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ELECTRICAL CHARACTERISTICS

PARAMETER	Symbol	Test Condition	MIN.	TYP.	MAX.	Units
Collector - Emitter Breakdown Voltage BC846AW,BW BC847AW/BW/CW,BC850BW/CW BC848AW/BW/CW,BC849BW/CW	$V_{(BR)CEO}$	$I_C=10mA, I_B=0$	65 45 30	-	-	V
Collector - Base Breakdown Voltage BC846AW,BW BC847AW/BW/CW,BC850BW/CW BC848AW/BW/CW,BC849BW/CW	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0$	80 50 30	-	-	V
Emitter - Base Breakdown Voltage BC846AW,BW BC847AW/BW/CW,BC850BW/CW BC848AW/BW/CW,BC849BW/CW	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0$	6.0 6.0 5.0	-	-	V
Emitter-Base Cutoff Current	I_{EBO}	$V_{EB}=5$	-	-	100	nA
Collector-Base Cutoff Current	I_{CBO}	$V_{CB}=30V, I_E=0$ $V_{CB}=30V, I_E=0, T_J=150^\circ C$	-	-	15 5.0	nA μA
DC Current Gain BC846~BC848 Suffix "AW" BC846~BC850 Suffix "BW" BC847~BC850 Suffix "CW"	h_{FE}	$I_C=10\mu A, V_{CE}=5V$	-	90 150 270	-	-
DC Current Gain BC846~BC848 Suffix "AW" BC846~BC850 Suffix "BW" BC847~BC850 Suffix "CW"	h_{FE}	$I_C=2.0mA, V_{CE}=5V$	110 200 420	180 290 520	220 450 800	-
Collector - Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C=10mA, I_B=0.5mA$ $I_C=100mA, I_B=5.0mA$	-	-	0.25 0.6	V
Base - Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C=10mA, I_B=0.5mA$ $I_C=100mA, I_B=5.0mA$	-	0.7 0.9	-	V
Base - Emitter Voltage	$V_{CE(SAT)}$	$I_C=2mA, V_{CE}=5.0V$ $I_C=10mA, V_{CE}=5.0V$	0.58 -	0.660 -	0.70 0.77	V
Collector - Base Capacitance	C_{CBO}	$V_{CB}=10V, I_E=0, f=1MHz$	-	-	4.5	pF



BC846AW ~ BC850CW

ELECTRICAL CHARACTERISTICS CURVE (BC846AW,BC847AW,BC848AW)

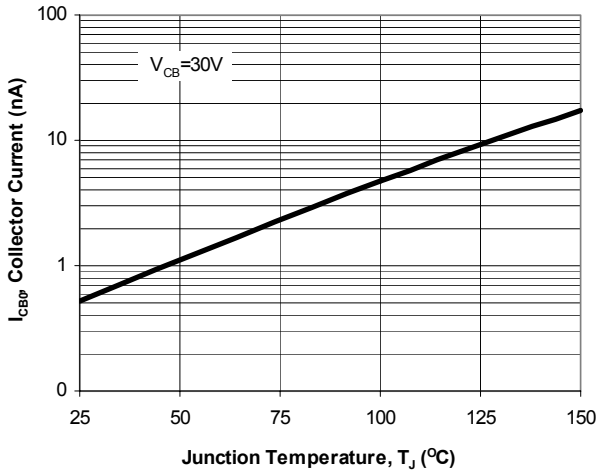


Fig. 1. Typical I_{CB0} vs. Junction Temperature

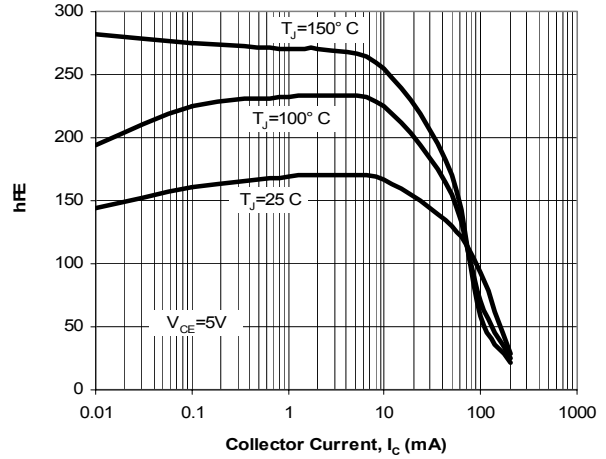


Fig. 2. Typical h_{FE} vs. Collector Current

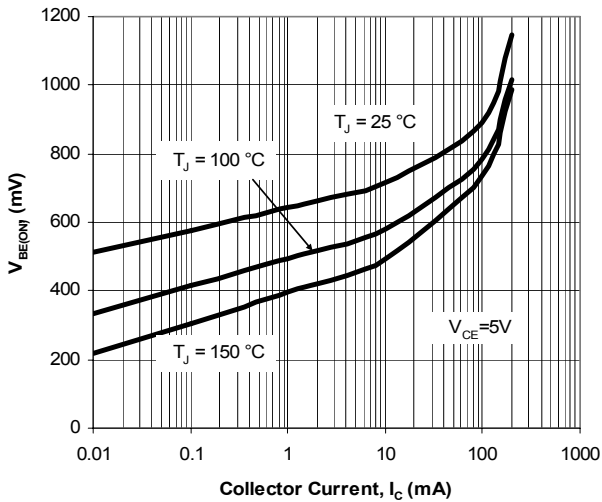


Fig. 3. Typical $V_{BE(ON)}$ vs. Collector Current

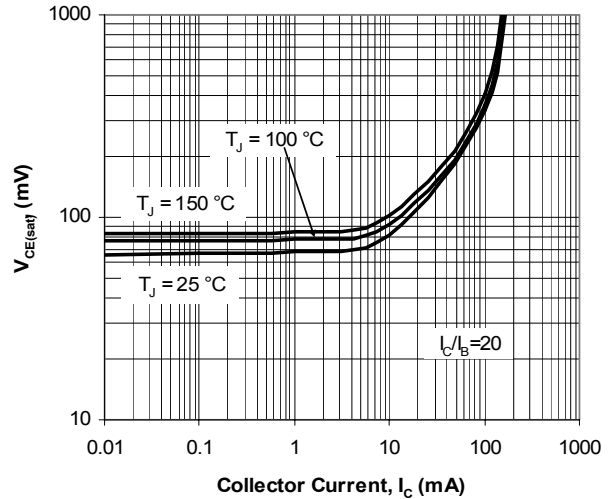


Fig. 4. Typical $V_{CE(SAT)}$ vs. Collector Current

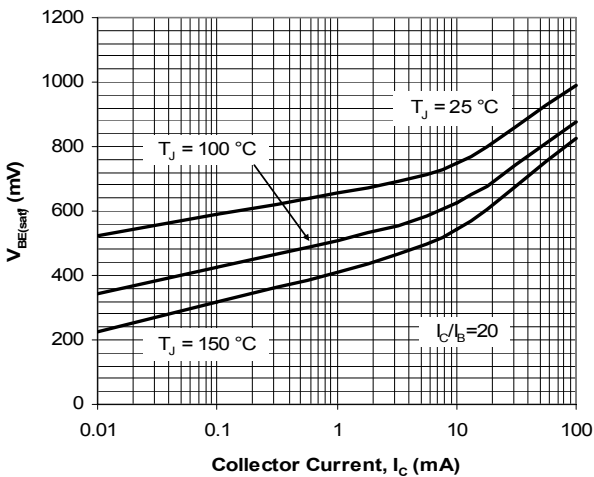


Fig. 5. Typical $V_{BE(SAT)}$ vs. Collector Current

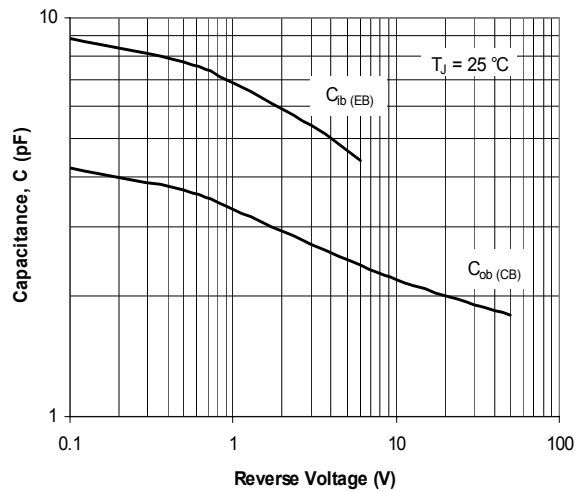


Fig. 6. Typical Capacitances vs. Reverse Voltage



BC846AW ~ BC850CW

ELECTRICAL CHARACTERISTICS CURVE (BC846BW,BAC847BW,BC848BW,BC849BW,BC850BW)

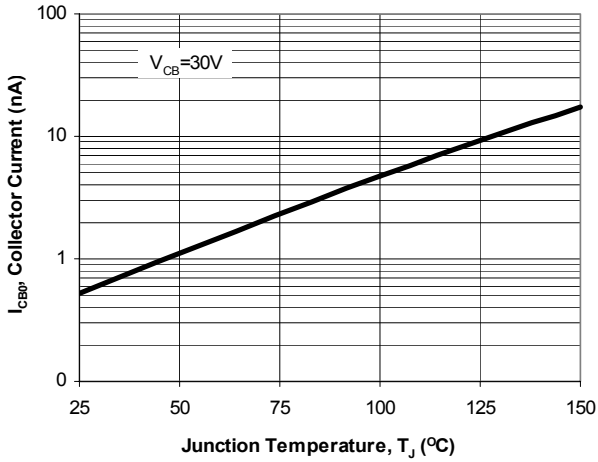


Fig. 1. Typical I_{CBO} vs. Junction Temperature

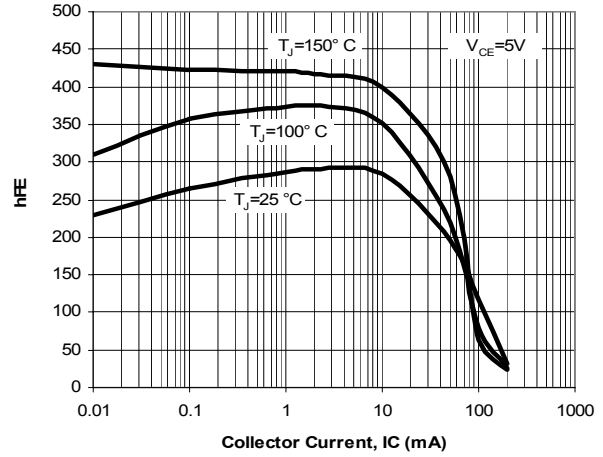


Fig. 2. Typical h_{FE} vs. Collector Current

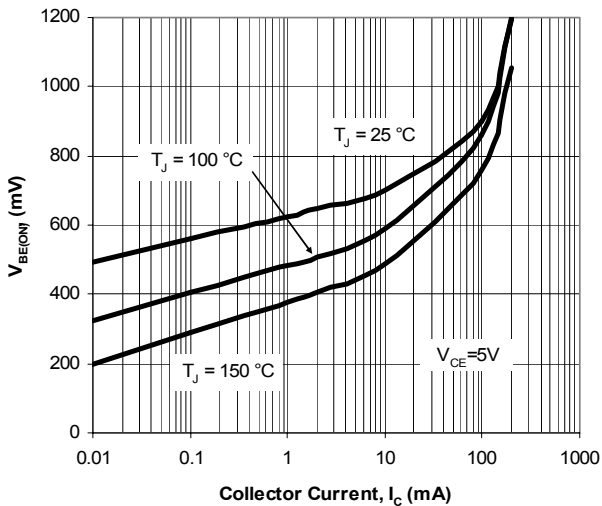


Fig. 3. Typical $V_{BE(ON)}$ vs. Collector Current

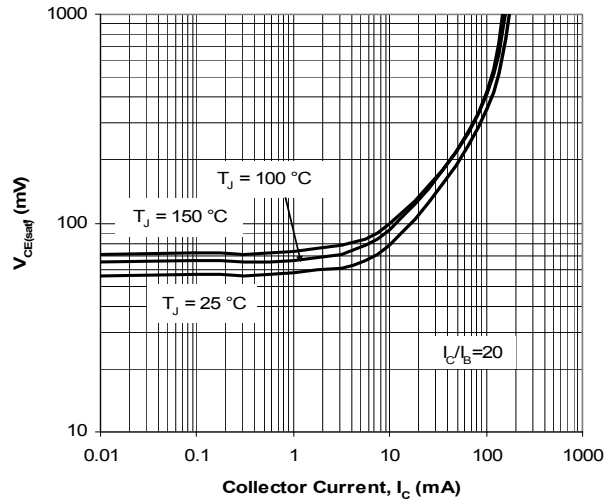


Fig. 4. Typical $V_{CE(SAT)}$ vs. Collector Current

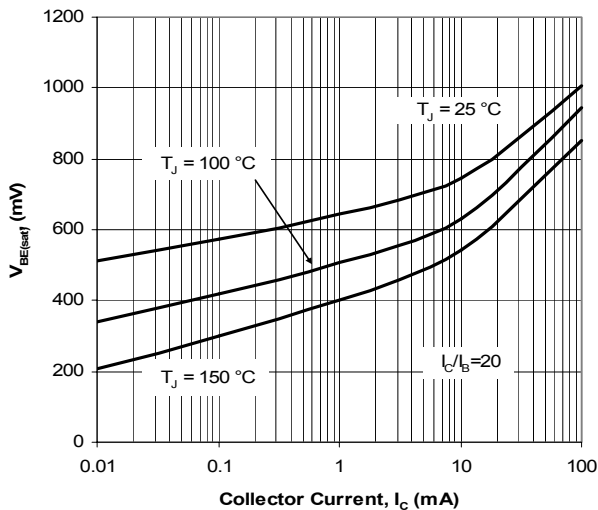


Fig. 5. Typical $V_{BE(SAT)}$ vs. Collector Current

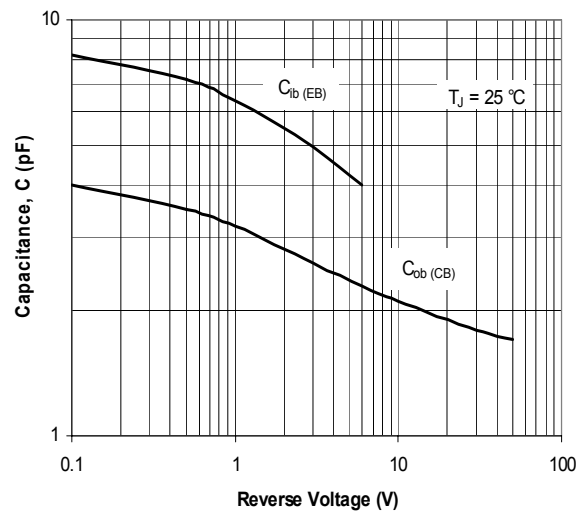


Fig. 6. Typical Capacitances vs. Reverse Voltage



BC846AW ~ BC850CW

ELECTRICAL CHARACTERISTICS CURVE (BAC847CW,BC848CW,BC849CW,BC850CW)

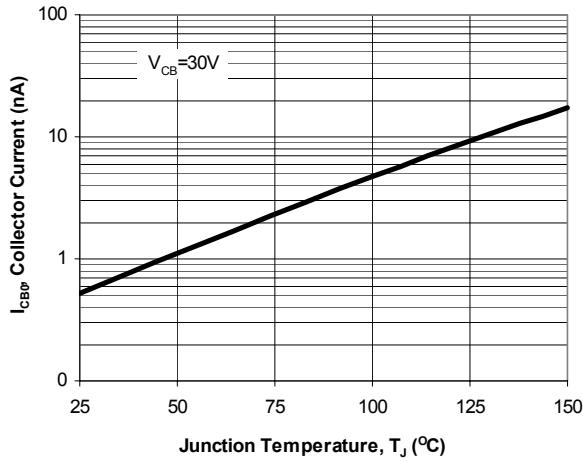


Fig. 1. Typical I_{CB0} vs. Junction Temperature

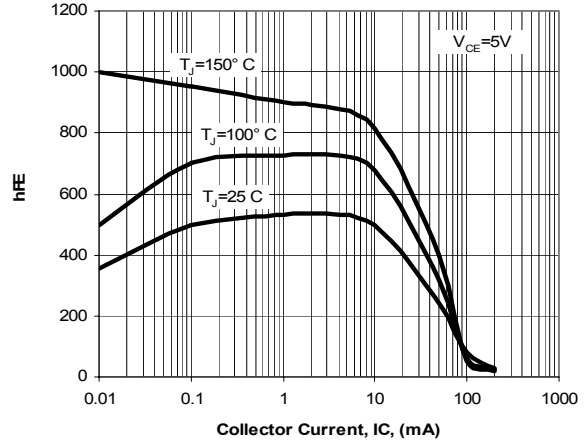


Fig. 2. Typical h_{FE} vs. Collector Current

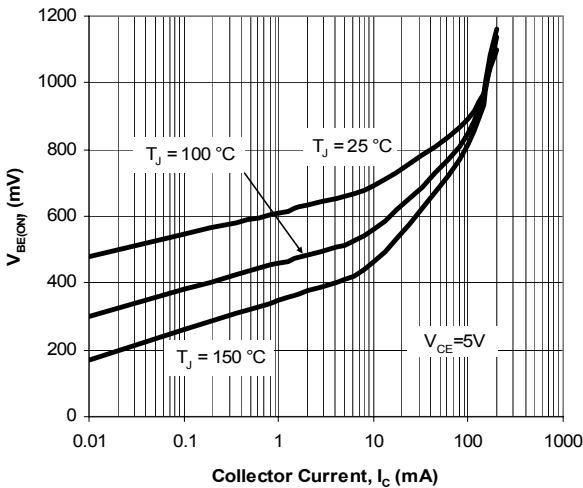


Fig. 3. Typical $V_{BE(ON)}$ vs. Collector Current

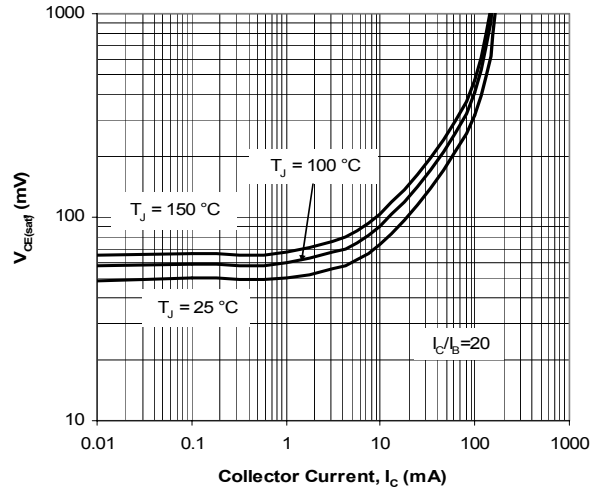


Fig. 4. Typical $V_{CE(SAT)}$ vs. Collector Current

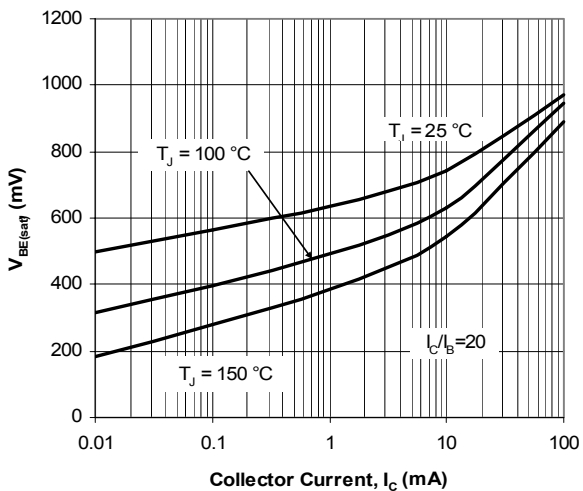


Fig. 5. Typical $V_{BE(SAT)}$ vs. Collector Current

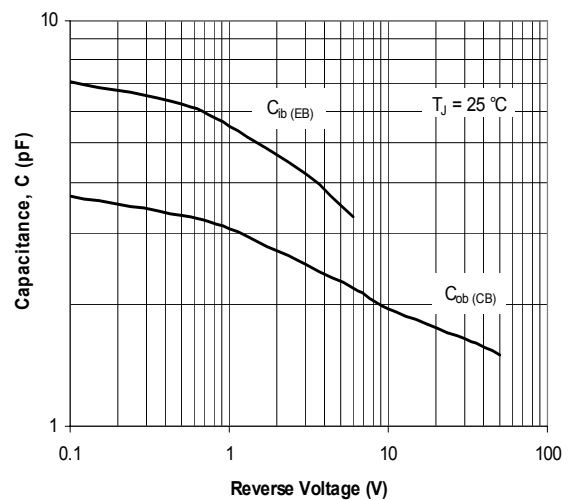
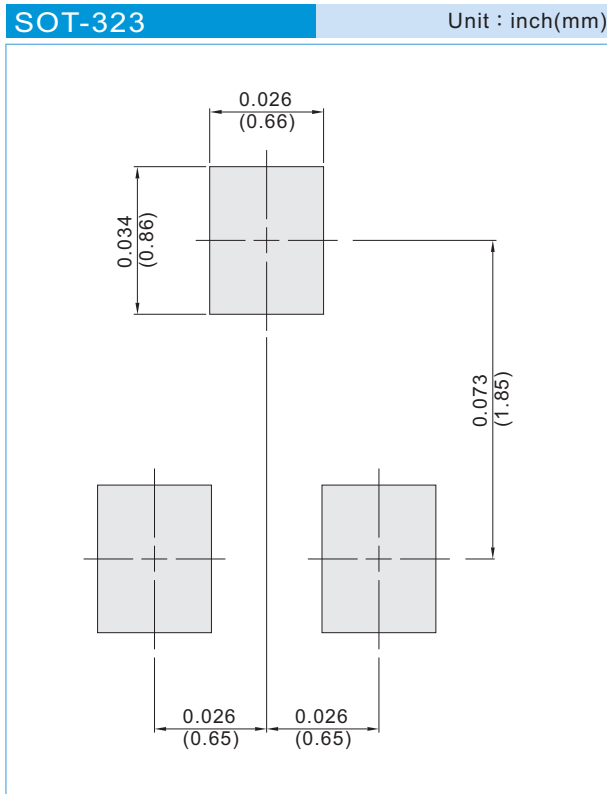


Fig. 6. Typical Capacitances vs. Reverse Voltage



BC846AW ~ BC850CW

MOUNTING PAD LAYOUT



ORDER INFORMATION

- Packing information
 - T/R - 12K per 13" plastic Reel
 - T/R - 3K per 7" plastic Reel

LEGAL STATEMENT

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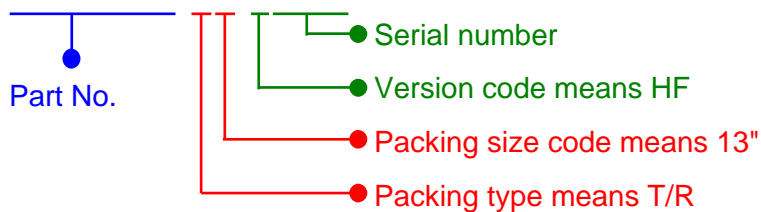


BC846AW ~ BC850CW

Part No_packing code_Version

For example :

RB500V-40_R2_0000%



Packing Code XX				Version Code XXXXX		
Packing type	1st Code	Packing size code	2nd Code	HF or RoHS	1st Code	2nd~5th Code
T/B	A	N/A	0	HF	0	serial number
T/R	R	7"	1	RoHS	1	serial number
B/P	B	13"	2			
T/P	T	26mm	X			
TRR	S	52mm	Y			
TRL	L	PBCU	U			
FORMING	F	PBCD	D			